Ordering number: ENN6092

TR: NPN Silicon Epitaxial Planar Transistor
SBD: Schottky Barrier Diode

CPH5703



DC/DC Converter Applications

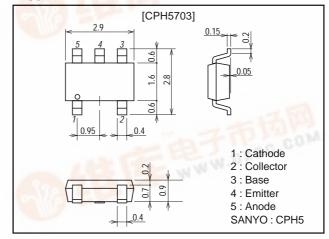
Features

- Composite type with a NPN transistor and a Schottky barrier diode contained in one package facilitating high-density mounting.
- The CPH5703 consists of two chips encapsulated in a package which are equivalent to the CPH3205 and the SB05-05CP, respectively.
- · Ultrasmall-sized package permitting applied sets to be made small and slim (0.9mm).

Package Dimensions

unit:mm

2156



Specifications

Absolute Maximum Ratings at Ta = 25°C

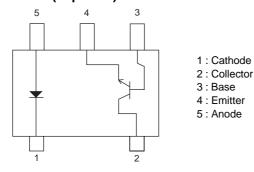
Parameter	Symbol	Conditions	Ratings		
[TR]					
Collector-to-Base Voltage	VCBO		60	V	
Collector-to-Emitter Voltage	VCEO	148	50	V	
Emitter-to-Base Voltage	V _{EBO}		6	V	
Collector Current	IC		3	Α	
Collector Current (Pulse)	ICP	AND ASSESSMENT OF THE PARTY OF	6	Α	
Base Current	IB	NO.	600	mA	
Collector Dissipation	PC	Mounted on a ceramic board (600mm²×0.8mm)	0.9	W	
Junction Temperature	Tj	Dist	150	°C	
Storage Temperature	Tstg	- Com	-55 to +125	°C	
[SBD]	M.D.		·		
Repetitive Peak Reverse Voltage	V _{RRM}		50	V	
Non-repetitive Peak Reverse Surge Voltage	V _{RSM}		55	V	
Average Output Current	Io		500	mA	
Surge Current	I _{FSM}	50Hz sine wave, 1 cycle	5	Α	
Junction Temperature	Tj		-55 to +125	°C	
Storage Temperature	Tstg	- 12 To 12 T	-55 to +125	°C	

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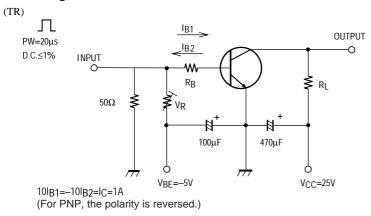
Electrical Characteristics at Ta = 25°C

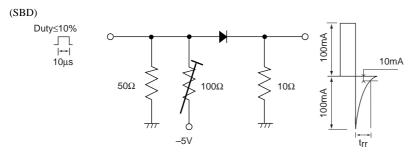
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Onit
[TR]						
Collector Cutoff Current	ICBO	V _{CB} =40V, I _E =0			1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =4V, I _C =0			1	μΑ
DC Current Gain	hFE	V _{CE} =2V, I _C =100mA	200		560	
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =500mA		380		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		13		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)} 1	I _C =1.0A, I _B =50mA		80	120	mV
	V _{CE(sat)} ²	I _C =2.0A, I _B =100mA		140	210	mV
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =1.0A, I _B =50mA		0.9	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0	60			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =1mA, R _{BE} =∞	50			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =10μA, I _C =0	6			V
Turn-ON Time	ton	See specified Test Circuit.		35		ns
Storage Time	t _{stg}	See specified Test Circuit.		300		ns
Turn-OFF Time	t _f	See specified Test Circuit.		22		ns
[SBD]	•					
Reverse Voltage	V _R	I _R =200μA	50			V
Forward Voltage	VF	I _F =500mA			0.55	V
Reverse Current	I _R	V _R =25V			50	μΑ
Interterminal Capacitance	С	V _R =10V, f=1MHz		22		pF
Reverse Recovery Time	t _{rr}	I _F =I _R =100mA, See specified Test Circuit.			10	ns
Thermal Resistance	Rthj-a	Mounted on a ceramic board (600mm ² ×0.8mm)		151		°C/W

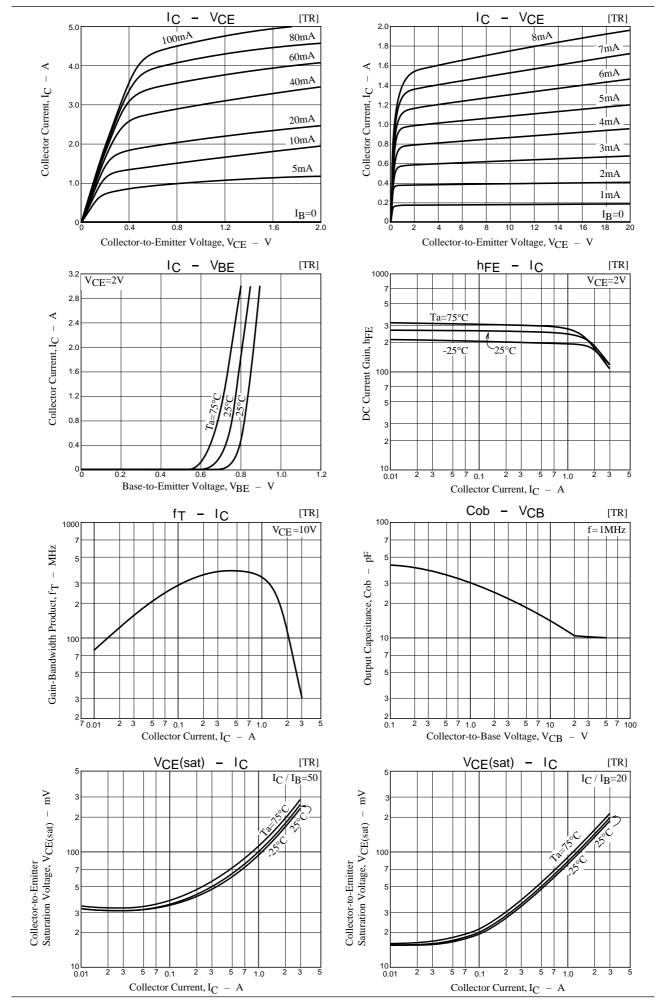
Electrical Connection (Top view)

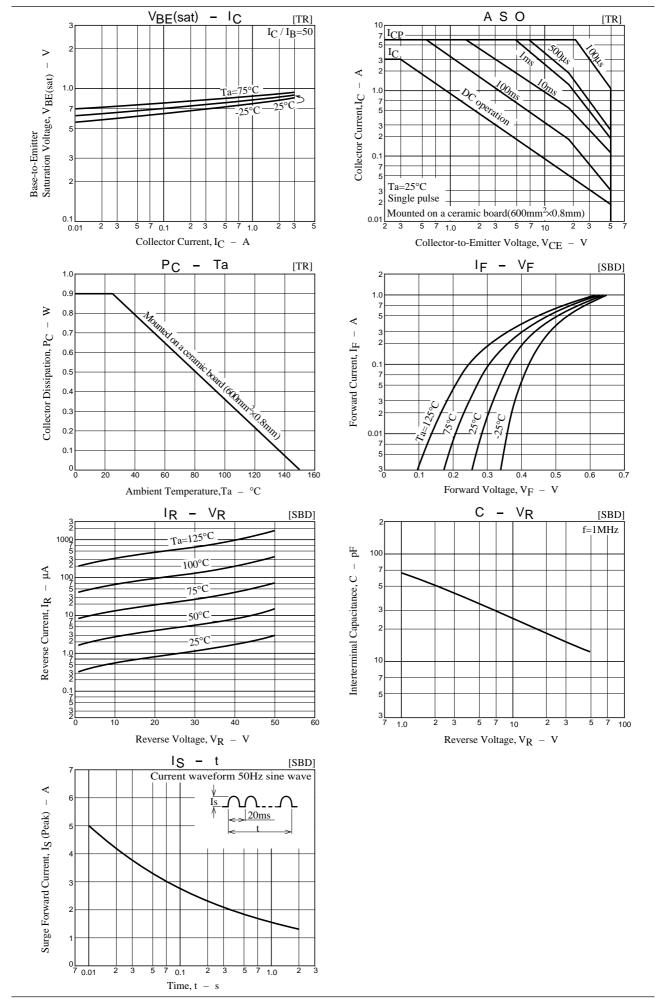


Switching Time Test Circuit









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